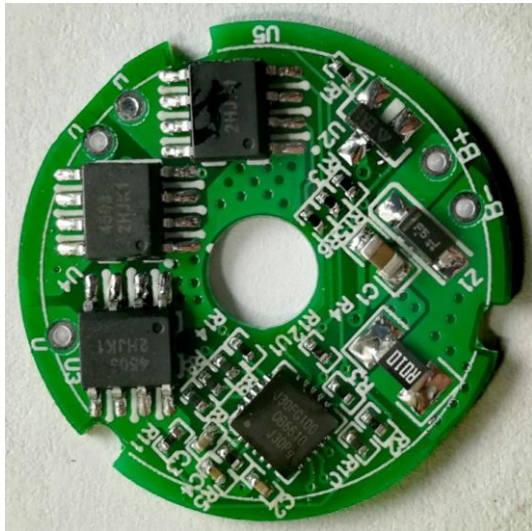


**Subject**  
**OB6610 Demo Board Manual**

Board Model: OB6610\_SO8\_1836  
Doc. No.: OB\_DOC\_DBM\_A\_661000



**Key Feature:**

- Sensorless motor control
- Continuous average current: 3.0A
- High speed motor support
- Motor start fast, stuck restart
- High precision and wide range speed control
- UVP/OCP support
- Fast phase to phase SCP
- Small PCB size, simple BOM and assemble conveniently

**Revision history:**

Revise Date	Version	Reason/Issue
2018-11-06	00	First Issue

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# 1. System Electrical Specification

## 1.1 Input Characteristic

- DC input voltage rating 1s Li-ion battery of 3.7V
- DC input voltage 2.8V to 4.2V

## 1.2 System parameters

- PWM frequency 25 KHz
- MCU supply voltage 2.8V to 4.2V
- Current sampling resistance  $15\text{m}\Omega \pm 1\%$
- Gate driver supply voltage 2.8V to 4.2V
- Max of MOSFET drain source voltage value 30.0V

## 1.3 Output characteristic

- Over average current 5.0A 3S
- Phase to phase shortcircuit average current 8.0A 40mS
- Restart times 3 times 1S interval
- Maximum of PWM duty 100%
- Minimum of PWM duty 13%

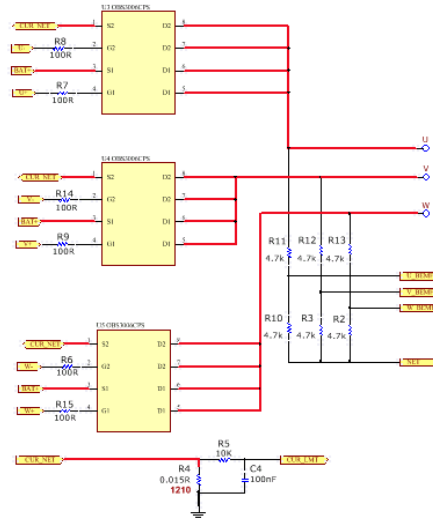
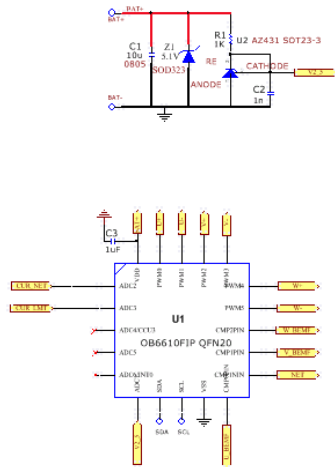
## 1.4 Environmental

- Operating Ambient Temperature  $-20\text{ }^{\circ}\text{C} \sim 45\text{ }^{\circ}\text{C}$
- Storage Temperature  $-40\text{ }^{\circ}\text{C} \sim 100\text{ }^{\circ}\text{C}$
- Storage Humidity 0 ~ 95% R.H.

## 2. Board Information

### 2.1 Schematic

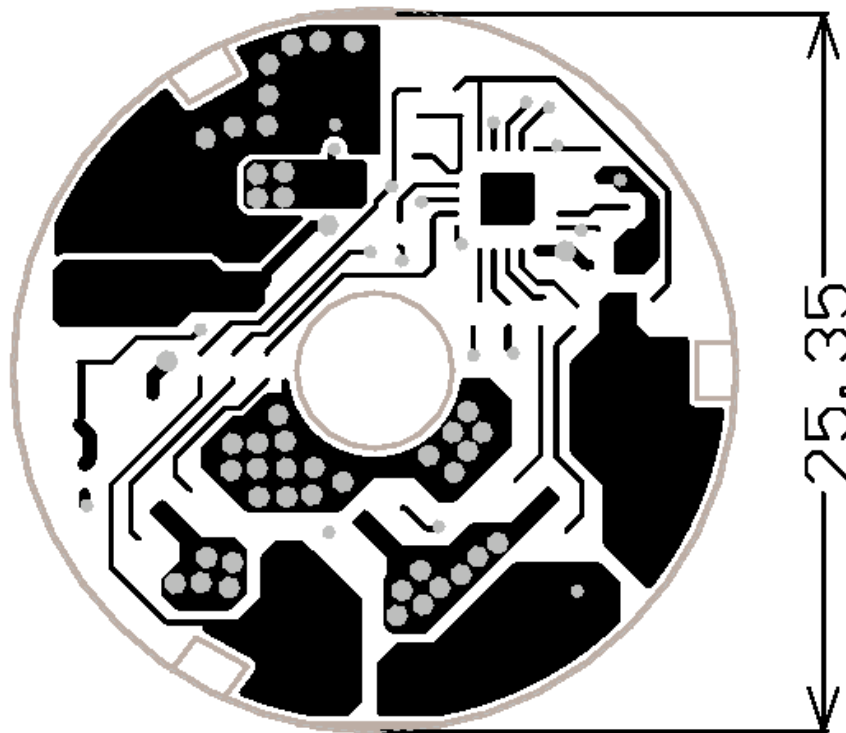
说明：  
 无源器件除特别说明都为 0402 ；  
 SDA/SCL 下载程序，背面焊点；  
 C1 靠近电池，C3 靠近 MCU VDD ；  
 MCU 背面基岛为 CMP1NIN ， LAYOUT 特别注意；  
 AZ431 PIN 脚定义特别注意，请参照 AZ TL413；



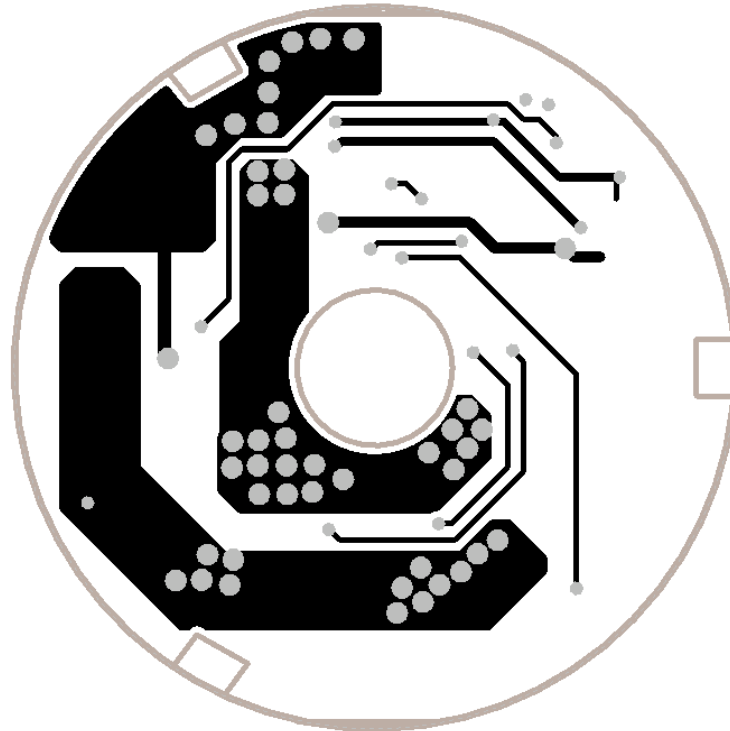
## 2.1.1 Bill of material

Designator	Package	Description	QTY
C1	C0805	Capacitor,ceramic,10uF/25V	1
Z1	SOD323	Zener,5.1V	1
C2	C0402	Capacitor,ceramic,1nF/25V	1
C3	C0402	Capacitor,ceramic,1uF/25V	1
C4	C0402	Capacitor,ceramic,100nF/25V	1
R1	R0402	Resistor,chip,1K,1%	1
R2, R3, R10, R11, R12, R13	R0402	Resistor,chip,4.7K,1%	6
R4	R1210	Resistor,chip,0.015R,1%	1
R5	R0402	Resistor,chip,10K,1%	1
R6, R7, R8, R9, R14, R15	R0402	Resistor,chip,100R,1%	6
U1	QFN20	OB6610FIP	1
U2	SOT23-3	AZ431	1
U3, U4, U5	SOP-8	OBS3006CPS	3
PCB	26mm*26mm	1OZ , thickness 1.0mm	1

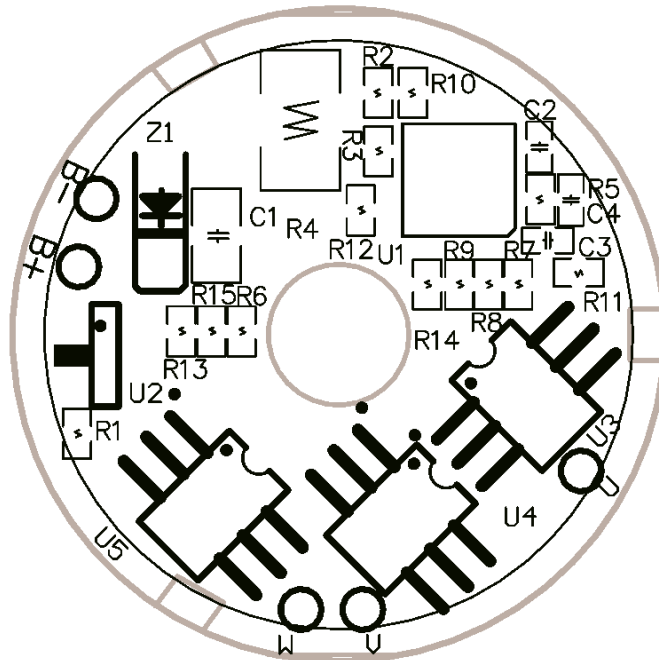
## 2.2 PCB Gerber File



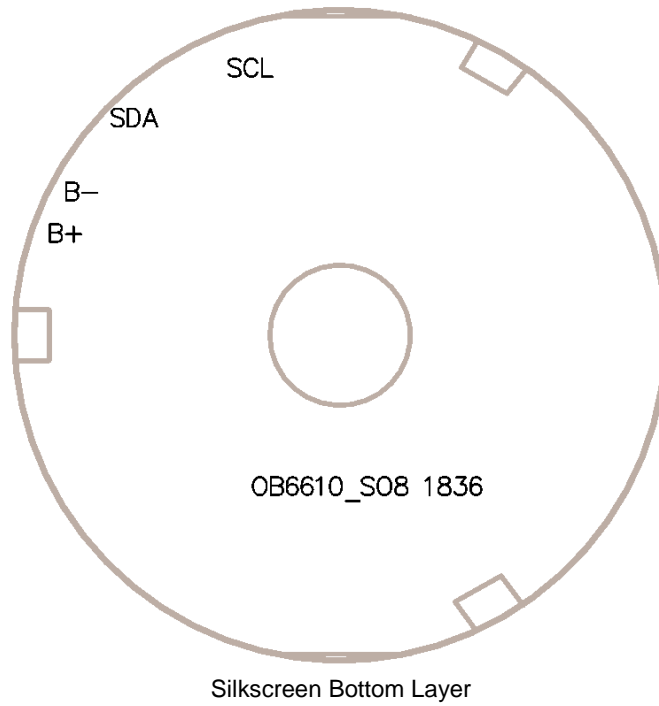
Top Layer



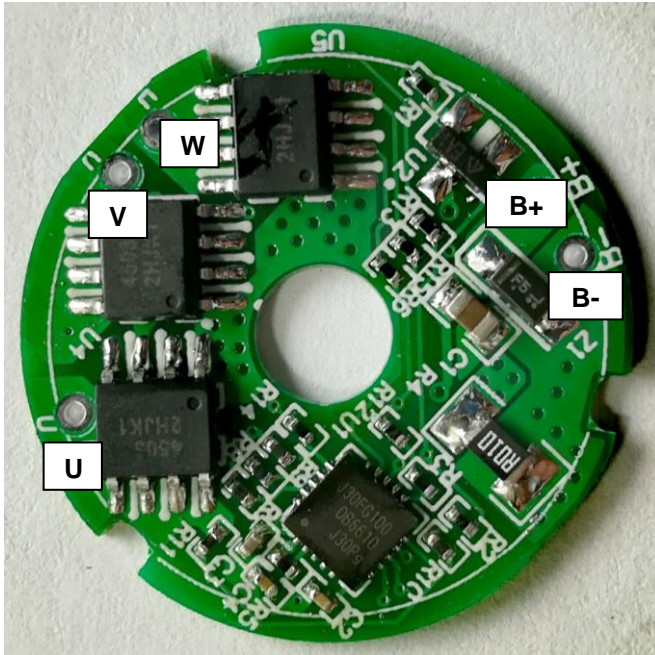
Bottom Layer



Silkscreen Top Layer

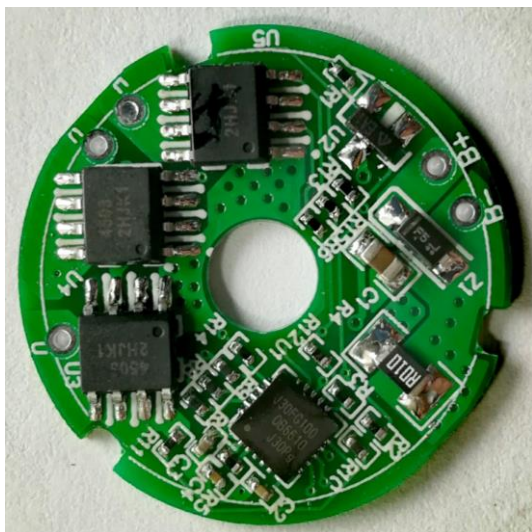


## 2.3 Interface Function Description



HoleName	Description
B+	Battery input, Bus+
B-	Battery input, GND
U	Motor U phase output
V	Motor V phase output
W	Motor W phase output

## 2.4 BLDC Controller Board Snapshot





### 3. Performance Evaluation

This session presents the test results of OB6610 3.7V/3.0A electronic trimmer controller demo. Results on inrush current and safety test are not included and will be added when they become available. Overall, the module meets design specifications.

TA=25°C

No	Parameter	Symbol	Min	Type	Max	Unit	Corresponding Fig.
1	MCU supply(Gate driver supply)	$V_{bat}$	2.8	3.7	4.2	V	Fig.1, Fig.2
2	Battery UVP	$V_{bus\_UVLO}$		2.8		V	Fig.3
3	MOSFET gate voltage	$V_{gs}$	1.0	1.6	3.0	V	Fig.4
4	Highside MOSFET rise time	$T_{r\_h}$		345.8		ns	Fig.4
5	Highside MOSFET fall time	$T_{f\_h}$		373.9		ns	Fig.4
6	Lowside MOSFET rise time	$T_{r\_l}$		195.9		ns	Fig.4
7	Lowside MOSFET fall time	$T_{f\_l}$		181.0		ns	Fig.4
8	Bus supply voltage spike	$V_{spike}$		1.0		V	Fig.5
9	PWM frequency	$f_{PWM}$		25.0		KHz	Fig.6
10	Motor stuck protect time	$T_{STP}$		66.7		ms	Fig.11

#### Test Equipments

Item	Module
Battery	1 cell Li-Iron, 2600mAH
DC source	GWINSTEK GPS-3303C
Oscilloscope	LeCroy 4024
Current meter	/
Differential probe	/
Thermo meter	DT-847U
Digital multimeter	FLUKE 15B+

### 3.1 Voltage Test

#### 3.1.1 MCU Supply(Gate Driver) Power ON/OFF & Vref Output

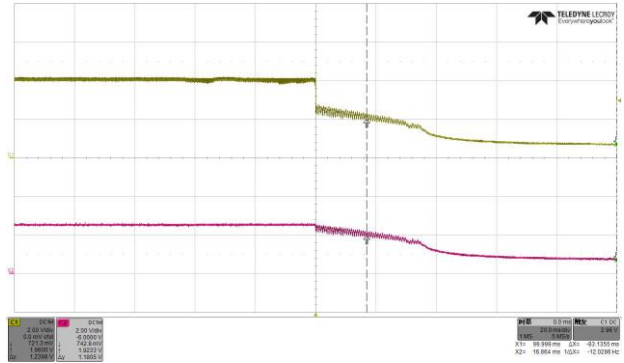
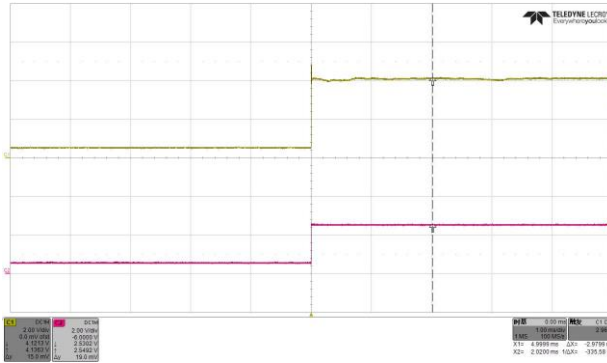


Fig. 1 Measured MCU supply voltage and 2.5V reference voltage @ battery=4.0V

Fig. 2 Measured MCU supply voltage and 2.5V reference voltage @ battery=4.0V

CH1:V<sub>BAT</sub> CH2:V<sub>REF</sub>

CH1:V<sub>BAT</sub> CH2:V<sub>REF</sub>

单节锂电接入，MCU 供电和 2.5V 采样参考电压输出正常波形

单节锂电移除，MCU 供电和 2.5V 采样参考电压输出正常波形

#### 3.1.2 V<sub>bus</sub> under voltage lockout

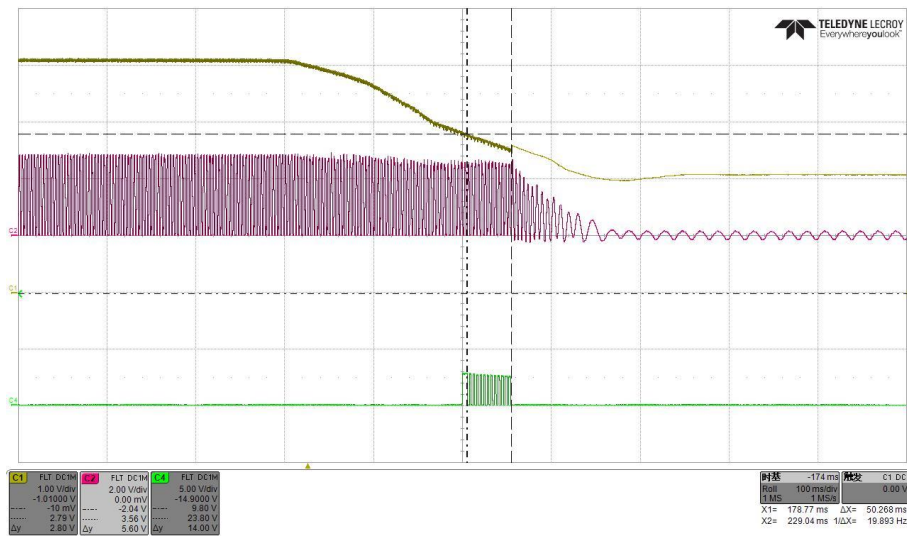


Fig. 3 Measured DC source voltage and U phase voltage @ V<sub>bus</sub>=4.2V

CH1:V<sub>BAT</sub> CH2:V<sub>MTR\_PHS</sub> CH4:2.8V UVP debounce counter

MCU 供电缓慢下降，欠压保护延时触发正常波形

### 3.1.3 MOSFET $V_{gs}/T_{r_h}/T_{r_l}/T_{f_h}/T_{f_l}$

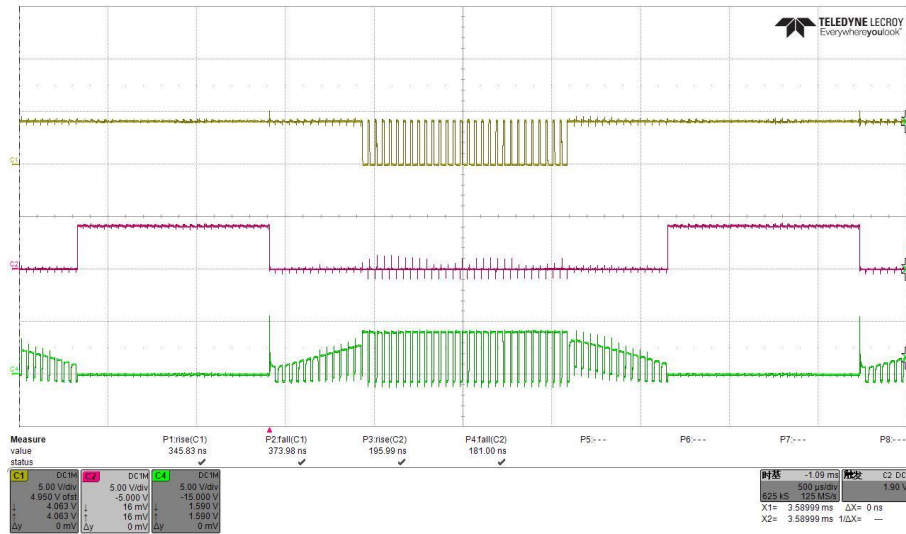


Fig. 4 Measured phase U highside and lowside MOSFET  $V_{gs}/T_{r_h}/T_{r_l}/T_{f_h}/T_{f_l}$

CH1:V<sub>GH</sub> CH2:V<sub>GL</sub> CH4:V<sub>MTR\_PHS</sub>

MCU 供电缓慢下降, 欠压保护延时触发正常波形

### 3.1.4 V<sub>bat</sub> Spike Voltage

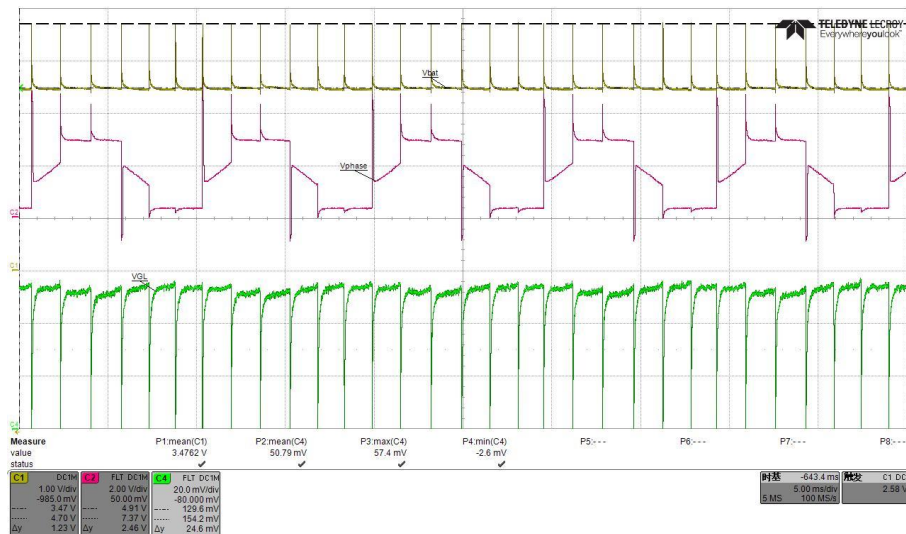


Fig. 5 Measured V<sub>bat</sub>/U phase voltage and R<sub>cs</sub> voltage

CH1:V<sub>BAT</sub> CH2:V<sub>MTR\_PHS</sub> CH4:I<sub>CS</sub>

100%占空比运行, 电池电压尖峰波形

## 3.2 PWM Test

### 3.2.1 PWM Frequency

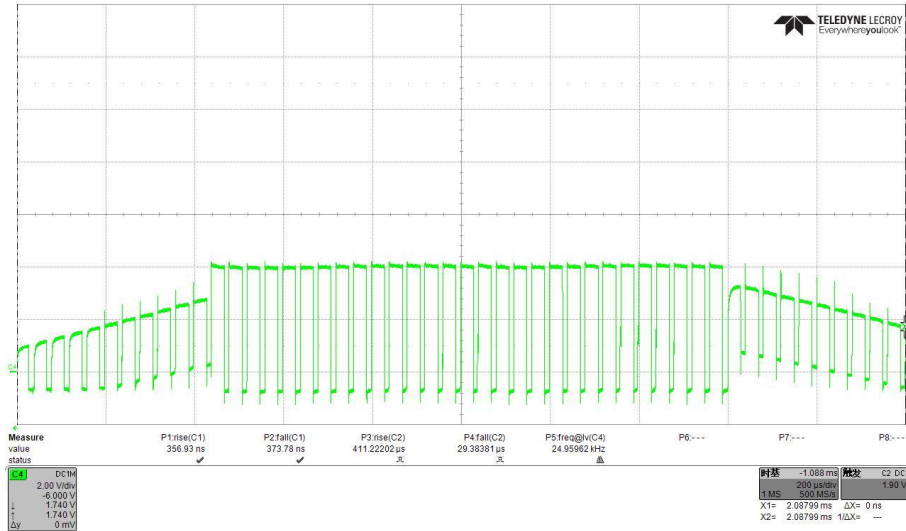


Fig. 6 Measured phase U voltage rising edge period

CH4:IMTR\_PHS

25.0KHz PWM 频率波形

### 3.2.2 Power On

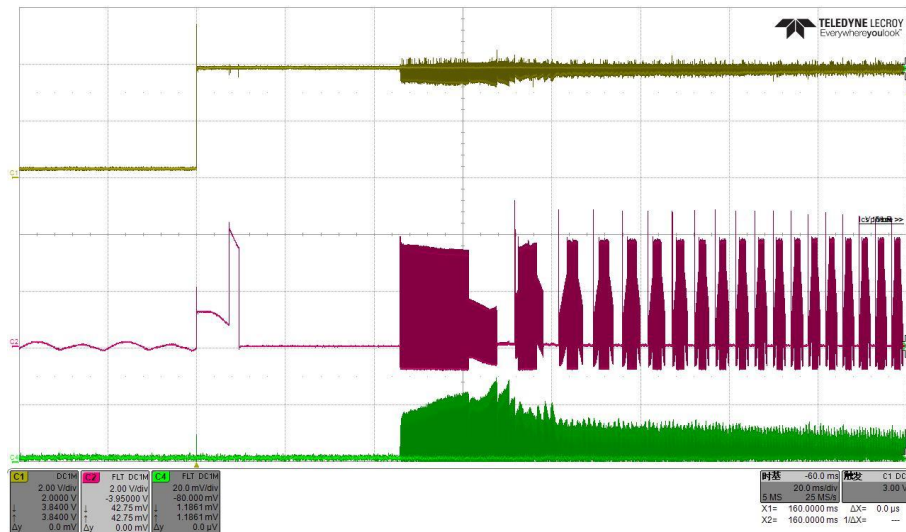


Fig. 7 Measured  $V_{bat}$  voltage / phase U voltage and  $R_{cs}$  voltage

CH1:V<sub>BAT</sub> CH2:V<sub>MTR\_PHS</sub> CH4:I<sub>CS</sub>

电机启动相电压和相电流波形

### 3.2.3 Power Off

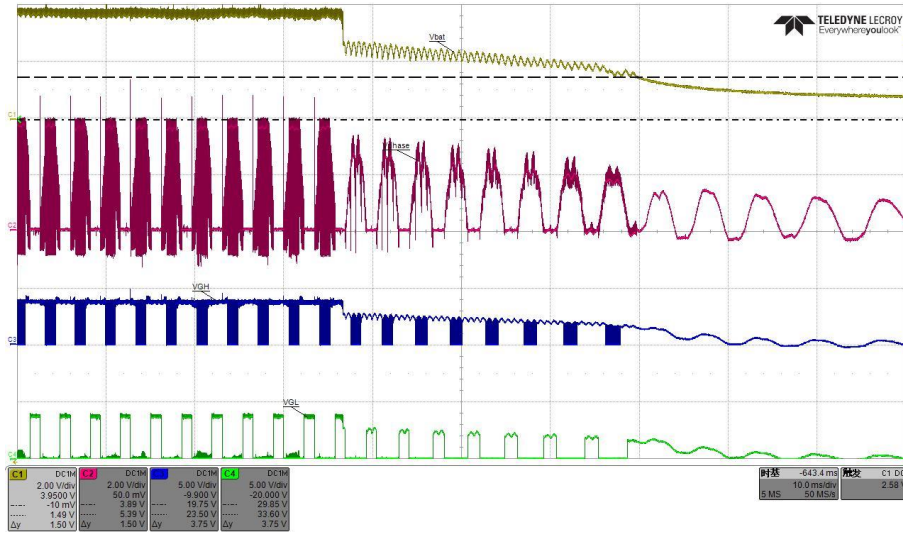


Fig. 8 Measured  $V_{bat}$  voltage / phase U voltage and highside / lowside gate drive voltage

CH1: $V_{BAT}$  CH2: $V_{MTR\_PHS}$  CH3: $V_{GH}$  CH4: $V_{GL}$

电池掉电过程电机相电压和上下管驱动波形

### 3.3 Current sampling

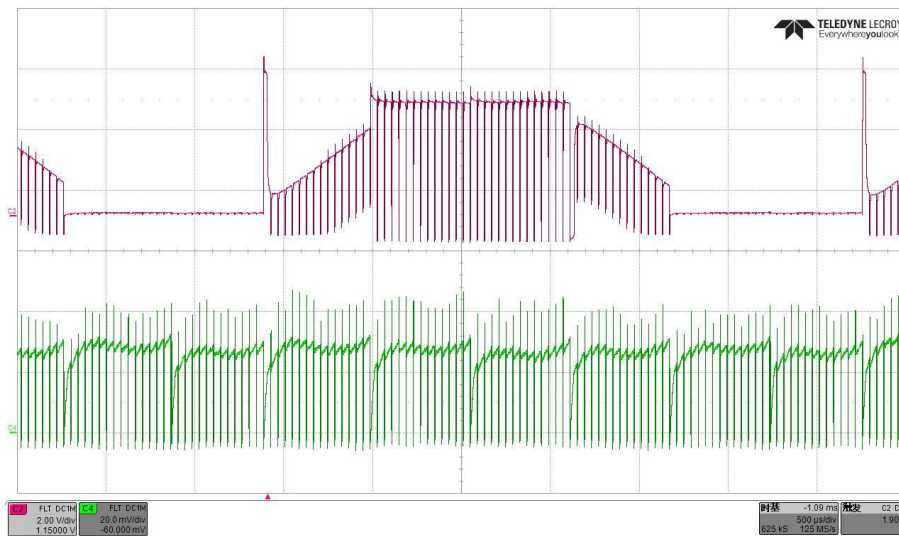


Fig. 9 Measured phase U voltage and  $R_{cs}$  voltage

CH2: $V_{MTR\_PHS}$  CH4: $I_{CS}$

电机驱动时电机相电压和电流采样电阻两端电压波形

### 3.4 Over Average Current Protect

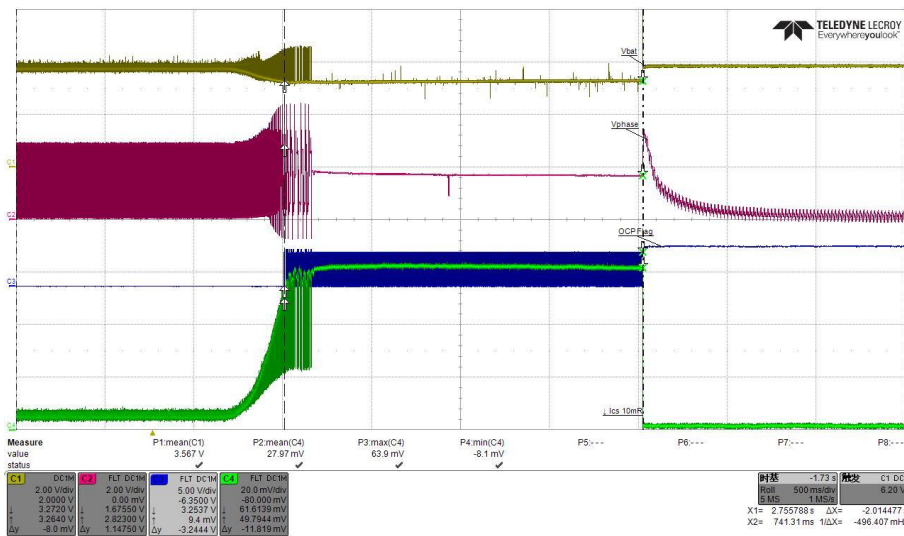


Fig. 10 Measured  $V_{bat}$ /phase U voltage/OCP debounce toggle counter and  $R_{cs}$  voltage

CH1:  $V_{BAT}$  CH2:  $V_{MTR\_PHS}$  CH3: OCP debounce counter CH4:  $I_{CS}$

电机慢速捏停过程电机相电流和过流保护波形

### 3.5 Motor Stuck Protect

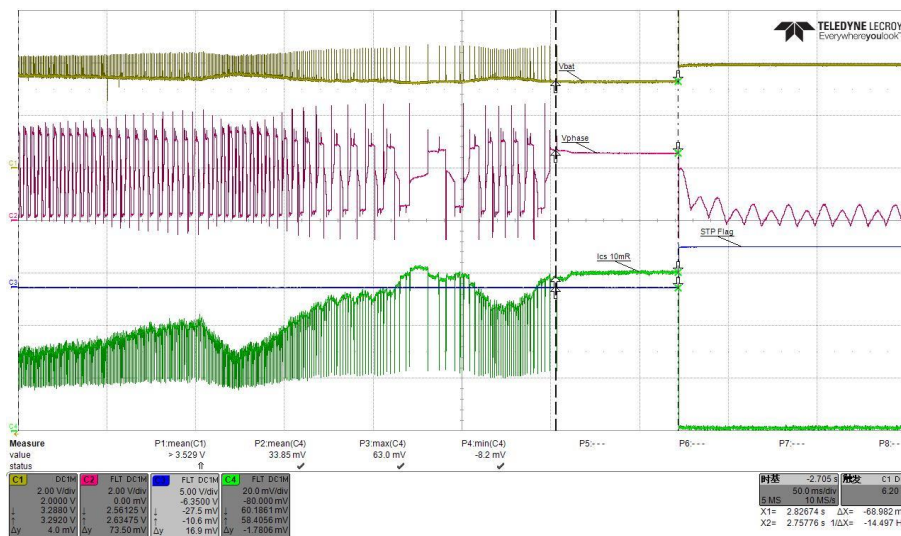


Fig. 11 Measured  $V_{bat}$ /phase U voltage/motor stuck protect flag and  $R_{cs}$  voltage

CH1:  $V_{BAT}$  CH2:  $V_{MTR\_PHS}$  CH3: OCP debounce counter CH4:  $I_{CS}$

电机快速捏停过程电机相电流和卡机保护波形



## 3.6 Motor Short Circuit Protection

### 3.6.1 U-V phase short circuit

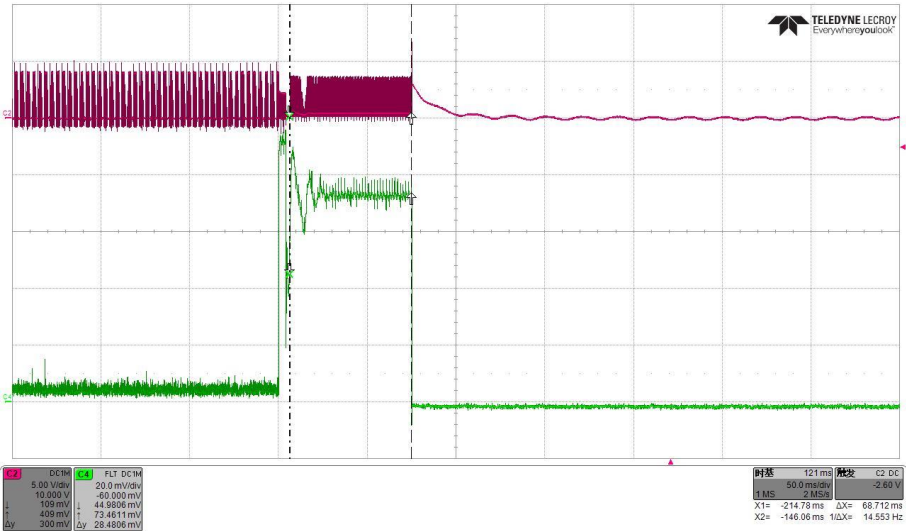


Fig. 12 Measured phase U voltage and  $R_{CS}$  voltage @ battery voltage = 4.0V

CH2:V<sub>MTR\_PHS</sub> CH4:I<sub>CS</sub>

U-V 相间短路时电流采样电阻两端电压和短路保护波形

### 3.6.2 U-W phase short circuit

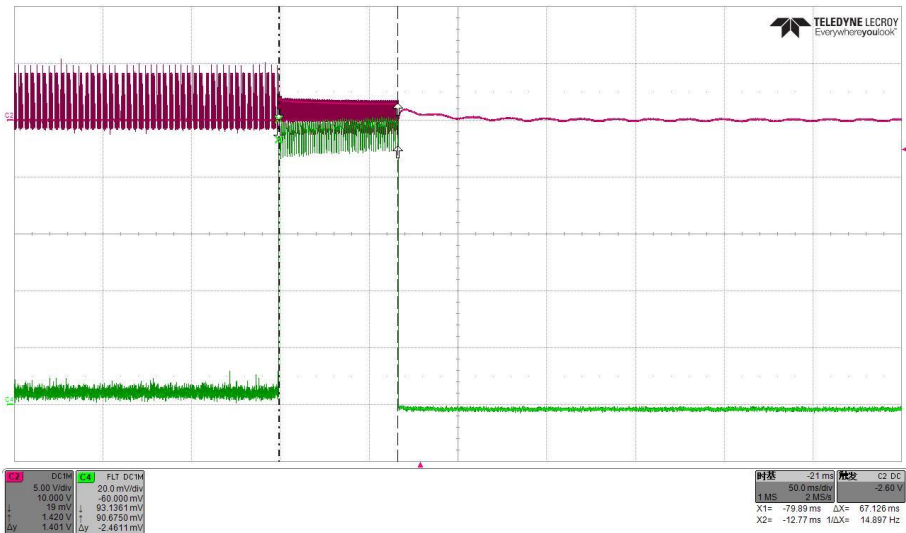


Fig. 13 Measured phase U voltage and  $R_{CS}$  voltage @ battery voltage = 4.0V

CH2:V<sub>MTR\_PHS</sub> CH4:I<sub>CS</sub>

U-W 相间短路时电流采样电阻两端电压和短路保护波形

### 3.6.3 V-W phase short circuit

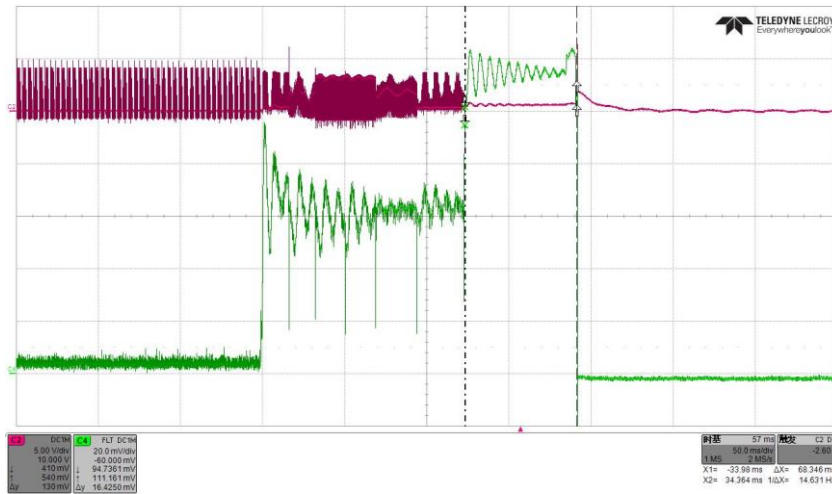


Fig. 14 Measured phase U voltage and  $R_{cs}$  voltage @ battery voltage = 4.0V

CH2:V<sub>MTR\_PHS</sub> CH4:I<sub>CS</sub>

V-W 相间短路时电流采样电阻两端电压和短路保护波形

## 3.7 Mosfet Temperature Rise

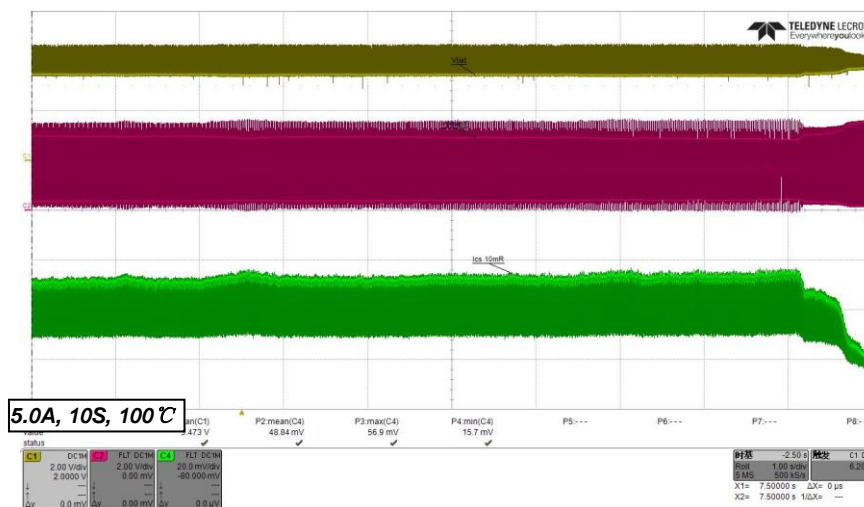


Fig. 15 Measured Bus voltage, U-phase voltage and  $R_{cs}$  voltage @ battery voltage = 4.0V

CH1:V<sub>BAT</sub> CH2:V<sub>MTR\_PHS</sub> CH4:I<sub>CS</sub>

室温 25°C 下 5.0A 平均电流持续工作 10S, 最高温度 MOS 约为 100°C

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